Features

- Fast read access time 120ns
- Dual voltage range operation
 - Low voltage power supply range, 3.0V to 3.6V, or
 - Standard power supply range, $5V \pm 10\%$
- Compatible with JEDEC standard Atmel[®] AT27C020
- Low-power CMOS operation
 - 20µA max standby (less than 1µA, typical) for V_{CC} = 3.6V
 - 29mW max active at 5MHz for V_{CC} = 3.6V
- JEDEC standard package
 - 32-lead PLCC
- High-reliability CMOS technology
 - 2,000V ESD protection
 - 200mA latchup immunity
- Rapid programming algorithm 100µs/byte (typical)
- Two-line control
- CMOS- and TTL-compatible inputs and outputs
 - JEDEC standard for LVTTL
- Integrated product identification code
- Industrial temperature range
- Green (Pb/halide-free) packaging option

1. Description

The Atmel AT27LV020A is a high-performance, low-power, low-voltage, 2,097,152-bit, one-time programmable, read-only memory (OTP EPROM) organized as 256K by 8 bits. It requires only one supply in the range of 3.0 to 3.6V in normal read mode operation, making it ideal for fast, portable systems using battery power.

The Atmel innovative design techniques provide fast speeds that rival 5V parts, while keeping the low power consumption of a 3V supply. At $V_{CC} = 3.0V$, any byte can be accessed in less than 120ns. With a typical power dissipation of only 18mW at 5MHz and $V_{CC} = 3.3V$, the AT27LV020A consumes less than one-fifth the power of a standard, 5V EPROM. Standby mode supply current is typically less than 1µA at 3.3V.

The AT27LV020A is available in an industry-standard, JEDEC-approved, one-time programmable (OTP) PLCC package. All devices feature two-line control (\overline{CE} , \overline{OE}) to give designers the flexibility to prevent bus contention.

The AT27LV020A operating with V_{CC} at 3.0V produces TTL-level outputs that are compatible with standard TTL logic devices operating at V_{CC} = 5.0V. The device is also capable of standard, 5V operation, making it ideally suited for dual supply range systems or card products that are pluggable in both 3V and 5V hosts.

The AT27LV020A has additional features to ensure high quality and efficient production use. The rapid programming algorithm reduces the time required to program the part and guarantees reliable programming. Programming time is typically only 100µs/byte. The integrated product identification code electronically identifies the device and manufacturer. This feature is used by industry standard programming equipment to select the proper





2Mb (256K x 8) Low Voltage, One-time Programmable, Read-only Memory

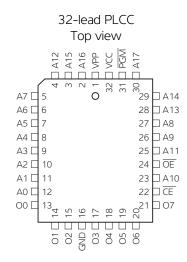
Atmel AT27LV020A

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programming algorithms and voltages. The AT27LV020A programs in exactly the same way as a standard, 5V Atmel AT27C020, and uses the same programming equipment.

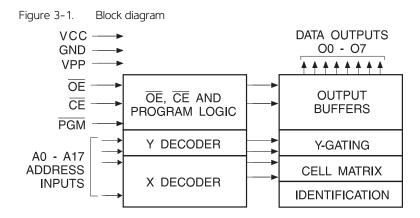
2. Pin configurations

Pin name	Function
A0 - A17	Addresses
00 - 07	Outputs
CE	Chip enable
ŌĒ	Output enable
PGM	Program strobe
NC	No connect



3. System considerations

Switching between active and standby conditions via the chip enable pin may produce transient voltage excursions. Unless accommodated by the system design, these transients may exceed datasheet limits, resulting in device nonconformance. At a minimum, a 0.1μ F, high-frequency, low inherent inductance, ceramic capacitor should be utilized for each device. This capacitor should be connected between the V_{CC} and ground terminals of the device, as close to the device as possible. Additionally, to stabilize the supply voltage level on printed circuit boards with large EPROM arrays, a 4.7μ F bulk electrolytic capacitor should be utilized, again connected between the V_{CC} and ground terminals. This capacitor should be positioned as close as possible to the point where the power supply is connected to the array.



4. Absolute maximum ratings*

Notes: 1 Minimum voltage is -0.6V DC which may unde
V _{PP} supply voltage with respect to ground2.0V to +14.0V ⁽¹⁾
Voltage on A9 with respect to ground2.0V to +14.0V ⁽¹⁾
Voltage on any pin with with respect to ground2.0V to +7.0V ⁽¹⁾
Storage temperature65°C to +125°C
Temperature under bias40°C to +85°C

- *NOTICE: Stresses beyond those listed under "Absolute maximum ratings" may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.
- Notes:
 Minimum voltage is -0.6V DC, which may undershoot to -2.0V for pulses of less than 20ns. Maximum output pin voltage is V_{CC} + 0.75V DC, which may be exceeded if certain precautions are observed (consult application notes), and which may overshoot to +7.0V for pulses of less than 20ns.

5. DC and AC characteristics

Table 5-1.	Operating modes
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Mode/Pin	CE	ŌĒ	PGM	Ai	V _{PP}	V _{cc}	Outputs
Read ⁽²⁾	VIL	V _{IL}	X ⁽¹⁾	Ai	Х	V _{CC}	D _{OUT}
Output disable ⁽²⁾	Х	V _{IH}	Х	Х	Х	V _{CC}	High Z
Standby ⁽²⁾	V _{IH}	Х	Х	Х	Х	V _{CC}	High Z
Rapid program ⁽³⁾	VIL	V _{IH}	V _{IL}	Ai	V _{PP}	V _{CC}	D _{IN}
PGM verify ⁽³⁾	VIL	V _{IL}	V _{IH}	Ai	V _{PP}	V _{CC}	D _{OUT}
PGM inhibit ⁽³⁾	V _{IH}	Х	Х	Х	V _{PP}	V _{CC}	High Z
Product identification ⁽³⁾⁽⁵⁾	V _{IL}	V _{IL}	х	$A9 = V_{H}^{(4)}$ $A0 = V_{H} \text{ or } V_{L}$ $A1 - A17 = V_{L}$	×	V _{cc}	Identification code

Notes: 1. X can be V_{IL} or V_{IH} .

- 2. Read, output disable, and standby modes require 3.0V \leq V_{CC} \leq 3.6V, or 4.5V \leq V_{CC} \leq 5.5V.
- 3. Refer to programming characteristics. Programming modes require V_{CC} = 6.5V.
- 4. $V_{H} = 12.0 \pm 0.5 V.$
- 5. Two identifier bytes may be selected. All Ai inputs are held low $(V_{||})$, except A9, which is set to V_{H} , and A0, which is toggled low $(V_{||})$ to select the manufacturer's identification byte and high $(V_{||})$ to select the device code byte.

	Atmel AT27LV020A-12
Industrial operating temperature (case)	-40°C - 85°C
	3.0V to 3.6V
V _{CC} power supply	5V ± 10%





Symbol	Parameter	Condition	Min	Max	Units
V _{CC} = 3.0V	to 3.6V				
I _{LI}	Input load current	$V_{IN} = 0V$ to V_{CC}		±1	μA
I _{LO}	Output leakage current	$V_{OUT} = OV \text{ to } V_{CC}$		± 5	μA
l _{PP1} (2)	V _{PP} read/standby current ⁽¹⁾	$V_{PP} = V_{CC}$		10	μA
)/(1)	I_{SB1} (CMOS), $\overline{CE} = V_{CC} \pm 0.3V$		20	μA
I _{SB}	V _{CC} standby current ⁽¹⁾	I_{SB2} (TTL), $\overline{CE} = 2.0$ to $V_{CC} + 0.5V$		100	μA
I _{cc}	V _{CC} active current	f = 5MHz, I_{OUT} = 0mA, \overline{CE} = V_{IL}		8	mA
V _{IL}	Input low voltage		-0.6	0.8	V
V _{IH}	Input high voltage		2.0	V _{CC} + 0.5	V
V _{OL}	Output low voltage	$I_{OL} = 2.0 \text{mA}$		0.4	V
V _{OH}	Output high voltage	I _{OH} = -2.0mA	2.4		V
V _{CC} = 4.5V	to 5.5V				
I _{LI}	Input load current	$V_{IN} = 0V$ to V_{CC}		±1	μA
I _{LO}	Output leakage current	$V_{OUT} = OV \text{ to } V_{CC}$		± 5	μA
(2) PP1	V _{PP} read/standby current ⁽¹⁾	$V_{PP} = V_{CC}$		10	μA
1)/(1)	I_{SB1} (CMOS), $\overline{CE} = V_{CC} \pm 0.3V$		100	μA
I _{SB}	V _{CC} standby current ⁽¹⁾	I_{SB2} (TTL), \overline{CE} = 2.0 to V_{CC} + 0.5V		1	mA
I _{cc}	V _{CC} active current	$f = 5MHz$, $I_{OUT} = 0mA$, $\overline{CE} = V_{IL}$		25	mA
V _{IL}	Input low voltage		-0.6	0.8	V
V _{IH}	Input high voltage		2.0	V _{CC} + 0.5	V
V _{OL}	Output low voltage	I _{OL} = 2.1mA		0.4	V
V _{OH}	Output high voltage	I _{OH} = -400μA	2.4		V

Table 5-3. DC and operating characteristics for read operation

Notes: 1. V_{CC} must be applied simultaneously with or before V_{PP} , and removed simultaneously with or after V_{PP} .

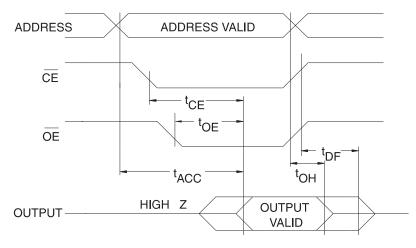
2. V_{PP} may be connected directly to $V_{CC'}$ except during programming. The supply current would then be the sun of I_{CC} and I_{PP} .

 $V_{\rm CC}$ = 3.0V to 3.6V and 4.5V to 5.5V

			Atmel AT27	LV020A-12	
Symbol	Parameter	Condition	Min	Max	Units
t _{ACC} ⁽³⁾	Address to output delay	$\overline{CE} = \overline{OE} = V_{IL}$		120	ns
t _{CE} ⁽²⁾	CE to output delay	$\overline{OE} = V_{IL}$		120	ns
t _{OE} ⁽²⁾⁽³⁾	OE to output delay	$\overline{CE} = V_{IL}$		50	ns
t _{DF} ⁽⁴⁾⁽⁵⁾	OE or CE high to output float, whichever occurred first			40	ns
t _{OH}	Output hold from address, CE or OE, hichever occurred first		0		ns

Table 5-4. AC characteristics for read operation

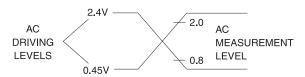
Figure 5-1. AC Waveforms for read operation



Notes: 1. Timing measurement references are 0.8V and 2.0V. Input AC drive levels are 0.45V and 2.4V, unless otherwise specified.

- 2. $\overline{\text{OE}}$ may be delayed up to t_{CE} t_{OE} after the falling edge of CE without impact on t_{CE} .
- 3. $\overline{\text{OE}}$ may be delayed up to t_{ACC} t_{OE} after the address is valid without impact on t_{ACC}
- 4. This parameter is only sampled, and is not 100% tested.
- 5. Output float is defined as the point when data is no longer driven.

Figure 5-2. Input test waveform and measurement level



 $t_{\rm R},\,t_{\rm F}<20$ ns (1% to 90%)

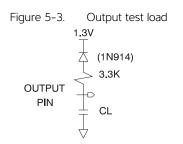




Table 5-5. Pin capacitance

 $f = 1MHz, T = 25^{\circ}C^{(1)}$

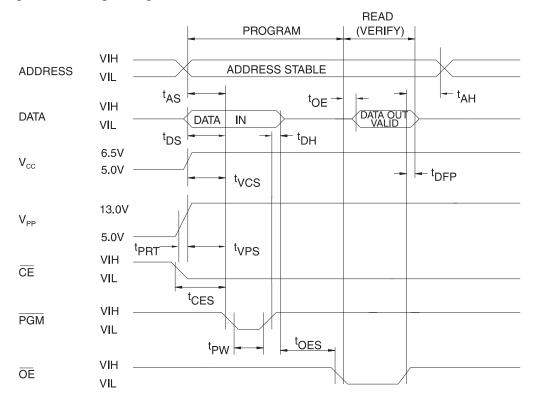
Symbol	Тур	Max	Units	Conditions
C _{IN}	4	8	pF	$V_{IN} = OV$
C _{OUT}	8	12	pF	$V_{OUT} = 0V$

Note: 1. Typical values for nominal supply voltage. This parameter is only sampled, and is not 100% tested.





Figure 5-4. Programming waveforms⁽¹⁾



Notes: 1. The input timing reference is 0.8V for $V_{\rm IL}$ and 2.0V for $V_{\rm IH}$

- 2. $t_{\rm OE}$ and $t_{\rm DFP}$ are characteristics of the device, but must be accommodated by the programmer.
- 3. When programming the Atmel AT27LV020A, a 0.1 μ F capacitor is required across V_{PP} and ground to suppress spurious voltage transients.

Table 5-6. DC programming characteristics

			Lir	Limits		
Symbol	Parameter	Test conditions	Min	Max	Units	
ILI	Input load current	$V_{IN}=V_{IL'}V_{IH}$		±10	μA	
V _{IL}	Input low level		-0.6	0.8	V	
V _{IH}	Input high level		2.0	V _{CC} + 0.5	V	
V _{OL}	Output low voltage	I _{OL} = 2.1mA		0.4	V	
V _{OH}	Output high voltage	I _{OH} = -400μA	2.4		V	
I _{CC2}	V _{CC} supply current (program and verify)			40	mA	
I _{PP2}	V _{PP} supply current	$\overline{CE} = \overline{PGM} = V_{IL}$		20	mA	
V _{ID}	A9 product identification voltage		11.5	12.5	V	

Table 5-7.AC programming characteristics

$T_A = 25 \pm 5^{\circ}C$, $V_{CC} = 6.5 \pm 0.25V$, $V_{PP} = 13.0 \pm 0.25V$

			Lin	nits	
Symbol	Parameter	Test conditions ⁽¹⁾	Min	Max	Units
t _{AS}	Address setup time		2		μs
t _{CES}	CE setup time		2		μs
t _{OES}	OE setup time	Input rise and fall times	2		μs
t _{DS}	Data setup time	(10% to 90%) 20ns Input pulse levels 0.45V to 2.4V Input timing reference level 0.8V to 2.0V Output timing reference level 0.8V to 2.0V	2		μs
t _{AH}	Address hold time		0		μs
t _{DH}	Data hold time		2		μs
t _{DFP}	OE high to output float delay ⁽³⁾		0	130	ns
t _{VPS}	V _{PP} setup time		2		μs
t _{VCS}	V _{CC} setup time		2		μs
t _{PW}	PGM program pulse width ⁽²⁾		95	105	μs
t _{OE}	Data valid from OE			150	ns
t _{PRT}	V_{PP} pulse rise time during programming		50		ns

Notes: 1. V_{CC} must be applied simultaneously with or before V_{PP} and removed simultaneously with or after V_{PP} .

2. This parameter is only sampled, and is not 100% tested. Output float is defined as the point where data is no longer driven. See timing diagram.

3. Program pulse width tolerance is $100\mu sec \pm 5\%$.

Table 5-8.	The Atmel AT27LV020A integrated product identification code ⁽¹⁾
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		Pins								
Codes	A0	07	O6	05	04	03	02	01	00	Hex data
Manufacturer	0	0	0	0	1	1	1	1	0	1E
Device type	1	1	0	0	0	0	1	1	0	86

Note: 1. The Atmel AT27LV020A has the same product identification code as the Atmel AT27C020. Both are programming compatible.

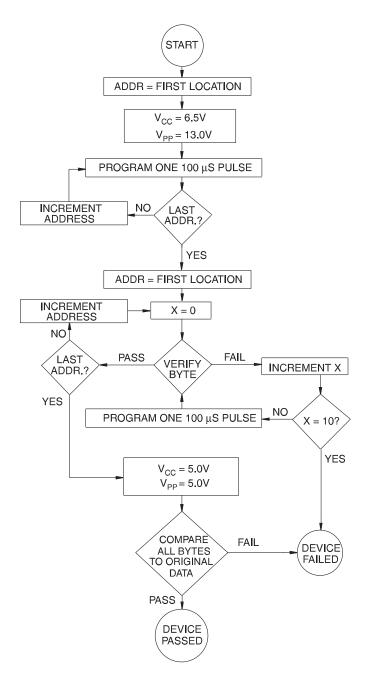


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6. Rapid programming algorithm

A 100µs \overrightarrow{PGM} pulse width is used to program. The address is set to the first location. V_{CC} is raised to 6.5V and V_{PP} is raised to 13.0V. Each address is first programmed with one 100µs \overrightarrow{PGM} pulse without verification. Then a verification/reprogramming loop is executed for each address. In the event a byte fails to pass verification, up to 10 successive 100µs pulses are applied with a verification after each pulse. If the byte fails to verify after 10 pulses have been applied, the part is considered failed. After the byte verifies properly, the next address is selected until all have been checked. V_{PP} is then lowered to 5.0V and V_{CC} to 5.0V. All bytes are read again and compared with the original data to determine if the device passes or fails.

Figure 6-1. Rapid programming algorithm



7. Ordering Information

Green package option (Pb/halide-free)

t _{ACC}	I _{CC} (mA) V _{CC} = 3.6V						
(ns)	Active	Standby	Atmel ordering code	Package	Lead finish	Operation range	
120	8	0.02	AT27LV020A-12JU 32J Matte tin		Industrial (-40°C to 85°C)		

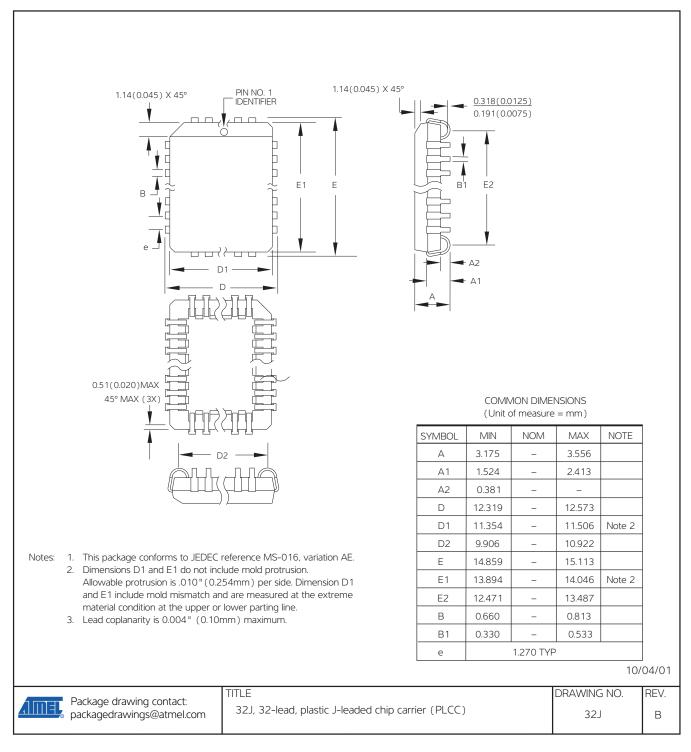
Package type				
32J 32-lead, plastic, J-leaded chip carrier (PLCC)				





8. Packaging information

32J – PLCC



9. Revision history

Doc. rev.	Date	Comments
0549H	04/2011	Remove TSOP and VSOP packages Add lead finish to ordering information
0549G	12/2007	

